

WEST Search History for Application 10797231

Creation Date: 2008121414:15

| Query | DB | Op. | Plur. | Thes. | Date |
|---|------------------------------------|-----|-------|-------|------------|
| (strained and MOSFET and SiGe) | USPT, USOC, EPAB, JPAB, DWPI, TDBD | ADJ | YES | | 12-11-2008 |
| ((strained and MOSFET and SiGe)) and (high k dielectric same "SiO.sub.2") | USPT, USOC, EPAB, JPAB, DWPI, TDBD | ADJ | YES | | 12-11-2008 |
| ((strained and MOSFET and SiGe)) and (high k dielectric same "SiO.sub.2" same gate) | USPT, USOC, EPAB, JPAB, DWPI, TDBD | ADJ | YES | | 12-11-2008 |
| ((strained and MOSFET and SiGe)) and (high k dielectric and ("SiO.sub.2" or oxide)) | USPT, USOC, EPAB, JPAB, DWPI, TDBD | ADJ | YES | | 12-11-2008 |
| ((strained and MOSFET and SiGe)) and (high k dielectric and ("SiO.sub.2" or oxide) and gate) | USPT, USOC, EPAB, JPAB, DWPI, TDBD | ADJ | YES | | 12-11-2008 |
| ((strained and MOSFET and SiGe)) and (high k dielectric and ("SiO.sub.2" or oxide) and gate) | USPT, USOC, EPAB, JPAB, DWPI, TDBD | ADJ | YES | | 12-11-2008 |
| (strain\$ and MOSFET and SiGe) | USPT, USOC, EPAB, JPAB, DWPI, TDBD | ADJ | YES | | 12-11-2008 |
| (MOSFET and SiGe) | USPT, USOC, EPAB, JPAB, DWPI, TDBD | ADJ | YES | | 12-11-2008 |
| ((MOSFET and SiGe)) and (high k dielectric and ("SiO.sub.2" or oxide) and gate) | USPT, USOC, EPAB, JPAB, DWPI, TDBD | ADJ | YES | | 12-11-2008 |
| (MODFET near10 MOSFET) and SiGe | USPT, USOC, EPAB, JPAB, DWPI, TDBD | ADJ | YES | | 12-14-2008 |
| (MODFET near10 MOSFET) and SiGe | USPT, USOC, EPAB, JPAB, DWPI, TDBD | ADJ | YES | | 12-14-2008 |